

## 1. General description

Planar passivated high commutation three quadrant triac in a SOT226A (I2PAK) plastic package intended for use in circuits where high static and dynamic dV/dt and high dl/dt can occur. This "series CT" triac will commutate the full RMS current at the maximum rated junction temperature  $(T_{j(max)} = 150 \ ^{\circ}C)$  without the aid of a snubber. It is used in applications where "high junction operating temperature capability" is required.

### 2. Features and benefits

- 3Q technology for improved noise immunity
- High commutation capability with maximum false trigger immunity
- High junction operating temperature capability (T<sub>j(max)</sub> = 150 °C)
- High voltage capability
- · Less sensitve gate for high noise immunity
- Planar passivated for voltage ruggedness and reliability
- Triggering in three quadrants only
- Very high immunity to false turn-on by dV/dt
- Package meets UL94V0 flammability requirement
- Package is RoHS compliant

### 3. Applications

- Applications subject to high temperature
- Electronic thermostats (heating and cooling)
- · High power motor controls e.g. washing machines and vacuum cleaners
- Rectifier-fed DC inductive loads e.g. DC motors and solenoids

## 4. Quick reference data

Table 1. Quick	reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>DRM</sub>	repetitive peak off- state voltage		-	-	600	V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; T <sub>mb</sub> ≤ 118 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	-	-	12	A
I <sub>TSM</sub>	non-repetitive peak on- state current	full sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>	-	-	100	A
		full sine wave; $T_{j(init)} = 25 \text{ °C};$ t <sub>p</sub> = 16.7 ms	-	-	110	A
Tj	junction temperature		-	-	150	°C
Static charact	eristics	·				

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>GT</sub>	gate trigger current	$V_D$ = 12 V; I <sub>T</sub> = 100 mA; T2+ G+; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	-	35	mA
		$V_D$ = 12 V; I <sub>T</sub> = 100 mA; T2+ G-; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	-	35	mA
		V <sub>D</sub> = 12 V; I <sub>T</sub> = 100 mA; T2- G-; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	-	35	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	-	35	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 15 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	-	1.6	V
Dynamic ch	naracteristics	·				
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 402 V; T <sub>j</sub> = 150 °C; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform; gate open circuit	300	-	-	V/µs
dI <sub>com</sub> /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 150 \text{ °C}; \text{ I}_{T(RMS)} = 12 \text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu\text{s}; \text{ (snubberless condition); gate open circuit}$	8	-	-	A/ms

## 5. Pinning information

#### Table 2. Pinning information Pin Symbol Description **Simplified outline Graphic symbol** 1 T1 main terminal 1 T2 T1 2 T2 main terminal 2 G 0 sym051 3 G gate T2 mb mounting base; main terminal 2 2 3 I2PAK (SOT226A)

## 6. Ordering information

Table 3. Ordering information					
Type number	Package				
	Name	Description	Version		
BTA312G-600CT	I2PAK	plastic single-ended package (I2PAK); TO-262	SOT226A		

## 7. Marking

Table 4. Marking codes	
Type number	Marking code
BTA312G-600CT	BTA312G-600CT

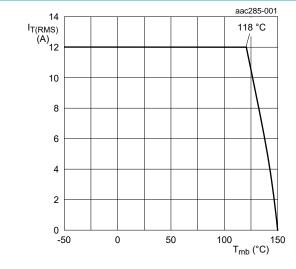


## 8. Limiting values

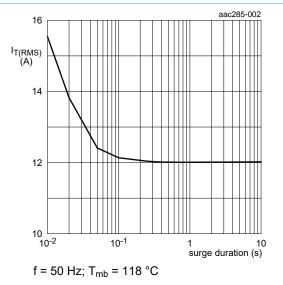
#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DRM</sub>	repetitive peak off-state voltage		-	600	V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; T <sub>mb</sub> ≤ 118 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	-	12	A
I <sub>TSM</sub>	non-repetitive peak on- state current	full sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 20 ms; Fig. 4; Fig. 5	-	100	A
		full sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 16.7 ms	-	110	А
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; sine-wave pulse	-	50	A²s
dl <sub>T</sub> /dt	rate of rise of on-state current	I <sub>G</sub> = 70 mA	-	100	A/µs
I <sub>GM</sub>	peak gate current	t = 20 μs	-	2	А
P <sub>GM</sub>	peak gate power		-	5	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period	-	0.5	W
T <sub>stg</sub>	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C

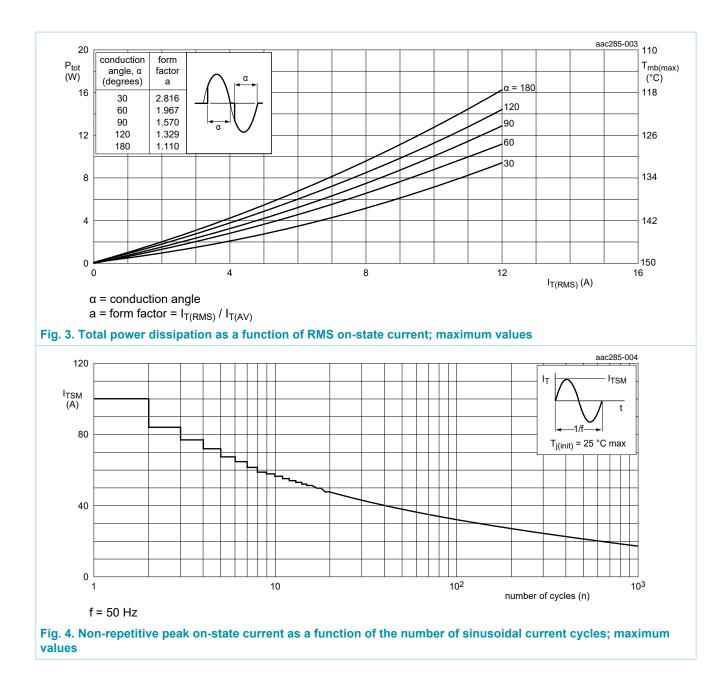








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### 9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	half cycle; <u>Fig. 6</u>	-	-	2.4	K/W
		full cycle; <u>Fig. 6</u>	-	-	2	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W

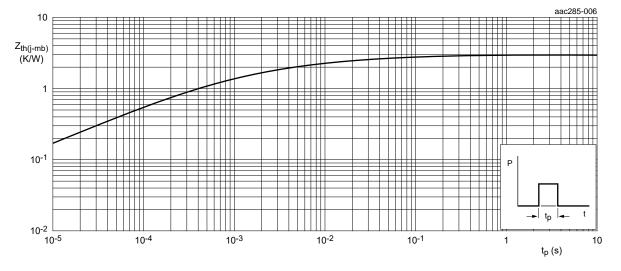


Fig. 6. Transient thermal impedance from junction to mounting base as a function of pulse duration

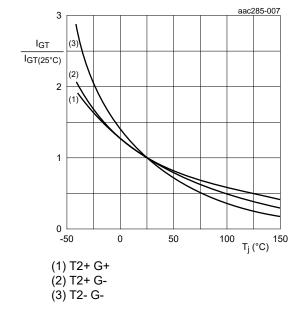
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## **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics				,	
I <sub>GT</sub>	gate trigger current	$V_D = 12 \text{ V}; \text{ I}_T = 100 \text{ mA}; \text{ T2+ G+};$ $T_j = 25 \text{ °C}; \text{ Fig. 7}$	-	-	35	mA
		$V_D = 12 \text{ V}; \text{ I}_T = 100 \text{ mA}; \text{ T2+ G-};$ T <sub>j</sub> = 25 °C; Fig. 7	-	-	35	mA
		$V_D = 12 \text{ V}; \text{ I}_T = 100 \text{ mA}; \text{ T2- G-};$ $T_j = 25 \text{ °C}; \frac{\text{Fig. 7}}{2}$	-	-	35	mA
IL	latching current	$V_D = 12 \text{ V}; \text{ I}_G = 100 \text{ A}; \text{ T2+ G+};$ T <sub>j</sub> = 25 °C; Fig. 8	-	-	50	mA
		$V_D = 12 \text{ V}; \text{ I}_G = 100 \text{ A}; \text{ T2+ G-};$ T <sub>j</sub> = 25 °C; Fig. 8	-	-	60	mA
		V <sub>D</sub> = 12 V; I <sub>G</sub> = 100 A; T2- G-; T <sub>j</sub> = 25 °C; <u>Fig. 8</u>	-	-	50	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	-	35	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 15 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	-	1.6	V
V <sub>GT</sub>	gate trigger voltage	$V_D = 12 \text{ V}; \text{ I}_T = 100 \text{ mA}; \text{ T}_j = 25 \text{ °C};$ Fig. 11	-	0.8	1	V
		V <sub>D</sub> = 400 V; I <sub>T</sub> = 100 mA; T <sub>j</sub> = 150 °C; <u>Fig. 11</u>	0.2	0.45	-	V
D	off-state current	V <sub>D</sub> = 600 V; T <sub>j</sub> = 25 °C	-	-	10	μA
		V <sub>D</sub> = 600 V; T <sub>j</sub> = 150 °C	-	0.4	2	mA
Dynamic ch	naracteristics					
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 402 V; T <sub>j</sub> = 150 °C; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform; gate open circuit	300	-	-	V/µs
dl <sub>com</sub> /dt	rate of change of commutating current	$V_D$ = 400 V; $T_j$ = 150 °C; $I_{T(RMS)}$ = 12 A; dV <sub>com</sub> /dt = 20 V/µs; (snubberless condition); gate open circuit	8	-	-	A/ms

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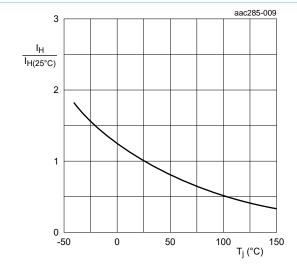
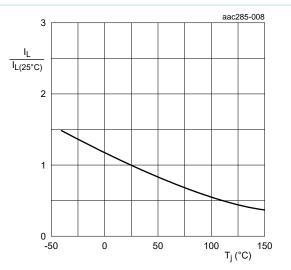
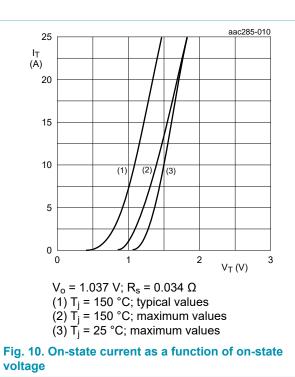


Fig. 9. Normalized holding current as a function of junction temperature

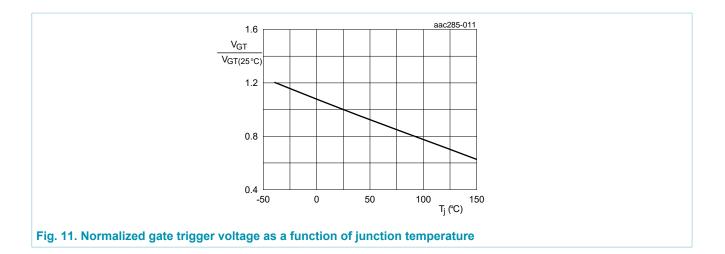






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## **11. Package outline**

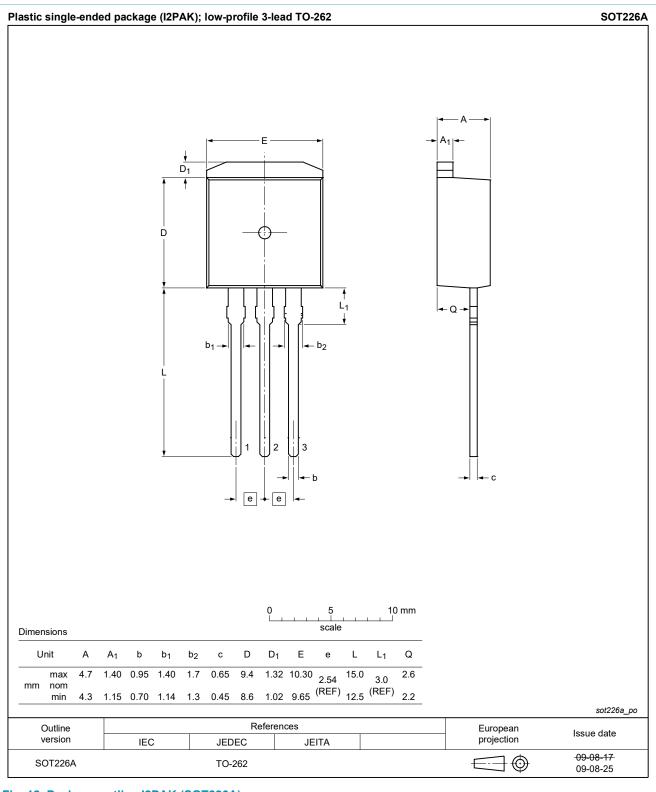


Fig. 12. Package outline I2PAK (SOT226A)

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#### **3Q Hi-Com Triac**

## 12. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [ <u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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[1] Please consult the most recently issued document before initiating or completing a design.

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